



7. CMOS fan out depends on
- (a) Power dissipation (b) Propagation delay  
(c) Current (d) Noise margin
8. The limit of a noise voltage which may be allowed in the circuit is
- (a) Noise Margin (b) Noise Voltage  
(c) Low level input noise (d) High level input noise
9. Sequential circuit output depends on
- (a) present input and feedback path (b) past input only  
(c) present input only (d) none of the above
10. The number of state variable 'm' produces
- (a)  $2^{m+1}$  states (b)  $2^{m-1}$  states (c)  $2^m$  states (d) None

PART - B (5 x 2 = 10 Marks)

11. Implement 2 input Ex-OR gate using NAND gate.
12. With truth table draw the circuit of 3-bit odd parity generator.
13. State the drawbacks of RS flip flop.
14. How does a static RAM differ from dynamic RAM?
15. What are the advantages of merging process?

PART - C (5 x 16 = 80 Marks)

16. (a) Simplify the following expression using Quine McCluskey method  
 $f [ w, x, y, z ] = \sum ( 0, 2, 3, 5, 6, 7, 8, 9 ) + d ( 10, 11, 12, 13, 14, 15 )$   
 Realize the minimized function using NOR gates only. (16)

Or

- (b) Consider the minimization of the following switching function using the QUINE-McCLUSKEY method.  $F(x_1, x_2, x_3, x_4) = \sum(0, 5, 7, 8, 9, 10, 11, 14, 15)$ . (16)
17. (a) (i) Construct the full adder using two half adders. (4)  
 (ii) Explain about the 4x1 multiplexer and Implement the function  
 $F (A, B, C) = \sum(1, 3, 5, 6)$  using a multiplexer. (12)

Or

(b) Design 4 bit Binary to BCD code converter. (16)

18. (a) Explain the working of 3-bit universal shift register with neat block diagram. (16)

Or

(b) Explain synchronous decade counter using T flip flop. (16)

19. (a) Briefly explain about PLD's with a suitable example. (16)

Or

(b) Explain synchronous decade counter using T flip flop. (16)

20. (a) Design a sequence detector circuit that produces an output 1 whenever the sequence 101101 is detected. (16)

Or

(b) Design serial binary adder using D-flip-flop. (16)

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